

DESCRIPTION

for surface mounting (SMD).

VSMF2893RGX01, VSMF2893GX01

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AUTOMOTIVE

ROHS

HALOGEN

FREE GREEN

(5-2008)

High Speed Infrared Emitting Diodes, 890 nm, GaAlAs, DH



VSMF2893X01 series are infrared, 890 nm emitting diodes

in GaAlAs (DH) technology with high radiant power and high

speed, molded in clear, untinted plastic packages (with lens)

FEATURES

- Package type: surface-mount
- Package form: GW, RGW
- Dimensions (L x W x H in mm): 2.3 x 2.3 x 2.55
- AEC-Q101 qualified
- Peak wavelength: $\lambda_p = 890 \text{ nm}$
- High reliability
- · High radiant power
- High radiant intensity
- Angle of half intensity: $\varphi = \pm 25^{\circ}$
- Low forward voltage
- · Suitable for high pulse current operation
- Terminal configurations: gullwing or reserve gullwing
- Package matches with detector VEMD2xx3X01 and VEMT2xx3X01 series
- Floor life: 4 weeks, MSL 2a, according to J-STD-020
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

APPLICATIONS

- IrDA compatible data transmission
- 3D TV
- IR touch panels
- Miniature light barrier
- Photointerrupters
- Optical switch
- Shaft encoders
- IR emitter source for proximity applications

PRODUCT SUMMARY							
COMPONENT	I _e (mW/sr)	$φ$ (deg) $λ_p$ (nm)		t _r (ns)			
VSMF2893RGX01	20	± 25	890	30			
VSMF2893GX01	20	± 25	890	30			

Note

• Test conditions see table "Basic Characteristics"

ORDERING INFORMATION							
ORDERING CODE	PACKAGING	REMARKS	PACKAGE FORM				
VSMF2893RGX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Reverse gullwing				
VSMF2893GX01	Tape and reel	MOQ: 6000 pcs, 6000 pcs/reel	Gullwing				

Note

• MOQ: minimum order quantity



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ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	VALUE	UNIT				
Reverse voltage		V_{R}	5	V				
Forward current		l _F	100	mA				
Peak forward current	$t_p/T = 0.5, t_p = 100 \mu s$	I _{FM}	200	mA				
Surge forward current	t _p = 100 μs	I _{FSM}	1	Α				
Power dissipation		P _V	160	mW				
Junction temperature		T _j	100	°C				
Operating temperature range		T _{amb}	-40 to +85	°C				
Storage temperature range		T _{stg}	-40 to +100	°C				
Soldering temperature	According to Fig. 9, J-STD-020	T _{sd}	260	°C				
Thermal resistance junction-to-ambient	J-STD-051, leads 7 mm, soldered on PCB	R _{thJA}	250	K/W				

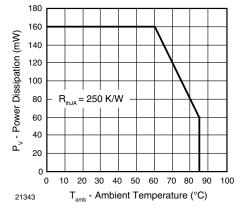


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

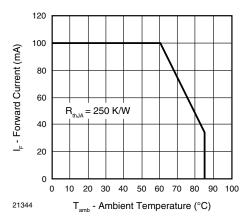


Fig. 2 - Forward Current Limit vs. Ambient Temperature

BASIC CHARACTERSITICS (T _{amb} = 25 °C, unless otherwise specified)								
PARAMETER	TEST CONDITION	SYMBOL	MIN.	TYP.	MAX.	UNIT		
Forward voltage	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	V_{F}	1.25	1.4	1.6	V		
Forward voltage	$I_F = 1 \text{ A}, t_p = 100 \ \mu \text{s}$	V_{F}		2.3		V		
Temperature apofficient of V	I _F = 1 mA	TK _{VF}		-1.8		mV/K		
Temperature coefficient of V _F	I _F = 100 mA	TK _{VF}	-1.8 mV/K -1.1 mV/K 10 μA 125 pF 10 20 30 mW/sr 180 mW/sr 40 mW -0.35 %/K ± 25 deg					
Reverse current	V _R = 5 V	I _R			10	μΑ		
Junction capacitance	$V_R = 0 \text{ V, f} = 1 \text{ MHz, E} = 0 \text{ mW/cm}^2$	CJ		125		pF		
Radiant intensity	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	l _e	10	20	30	mW/sr		
	$I_F = 1 \text{ A}, t_p = 100 \ \mu\text{s}$	l _e		180		mW/sr		
Radiant power	$I_F = 100 \text{ mA}, t_p = 20 \text{ ms}$	φ _е		40		mW		
Temperature coefficient of φ _e	I _F = 100 mA	TKφ _e		-0.35		%/K		
Angle of half intensity		φ		± 25		deg		
Peak wavelength	I _F = 30 mA	λ_{p}	870	890	910	nm		
Spectral bandwidth	I _F = 30 mA	Δλ		40		nm		
Temperature coefficient of λ_p	I _F = 30 mA	TKλ _p		0.25		nm/K		
Rise time	I _F = 100 mA, 20 % to 80 %	t _r		30		ns		
Fall time	I _F = 100 mA, 20 % to 80 %	t _f		30		ns		
Cut-off frequency	$I_{DC} = 70 \text{ mA}, I_{AC} = 30 \text{ mA pp}$	f _c		12		MHz		

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BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

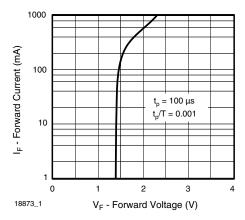


Fig. 3 - Forward Current vs. Forward Voltage

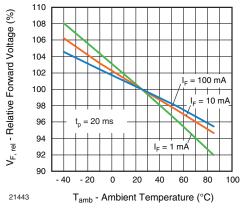


Fig. 4 - Relative Forward Voltage vs. Ambient Temperature

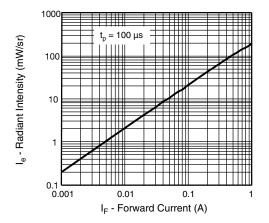


Fig. 5 - Radiant Intensity vs. Forward Current

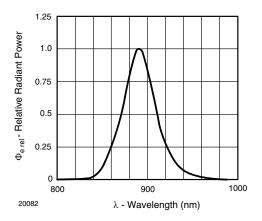


Fig. 6 - Relative Radiant Power vs. Wavelength

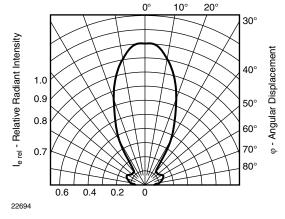


Fig. 7 - Relative Radiant Intensity vs. Angular Displacement

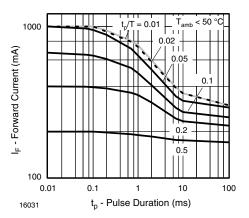


Fig. 8 - Pulse Forward Current vs. Pulse Duration

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SOLDER PROFILE

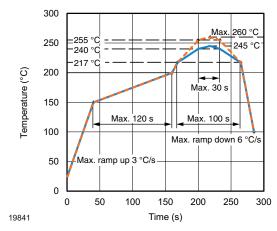


Fig. 9 - Lead (Pb)-free Reflow Solder Profile according to J-STD-020

DRYPACK

Devices are packed in moisture barrier bags (MBB) to prevent the products from moisture absorption during transportation and storage. Each bag contains a desiccant.

FLOOR LIFE

Floor life (time between soldering and removing from MBB) must not exceed the time indicated on MBB label:

Floor life: 4 weeks

Conditions: T_{amb} < 30 °C, RH < 60 %

Moisture sensitivity level 2a, according to J-STD-020.

DRYING

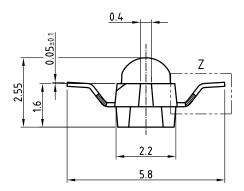
In case of moisture absorption devices should be baked before soldering. Conditions see J-STD-020 or label. Devices taped on reel dry using recommended conditions 192 h at 40 $^{\circ}$ C (+ 5 $^{\circ}$ C), RH < 5 $^{\circ}$ M.

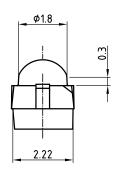


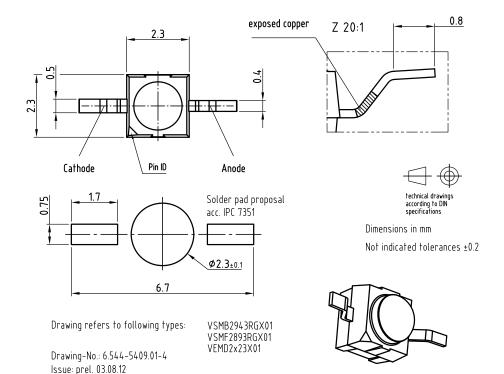
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PACKAGE DIMENSIONS in millimeters: VSMF2893RGX01





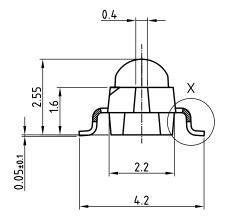


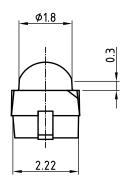


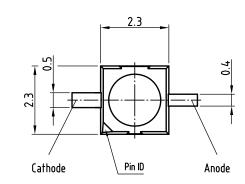
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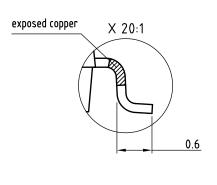
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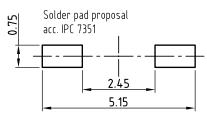
PACKAGE DIMENSIONS in millimeters: VSMF2893GX01













Not indicated tolerances ±0.2

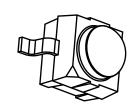
Drawing refers to following types:

VSMB2943GX01

Drawing-No.: 6.544-5408.01-4

Issue: prel; 03.08.12

VSMF2893GX01 VEMD2x23X01

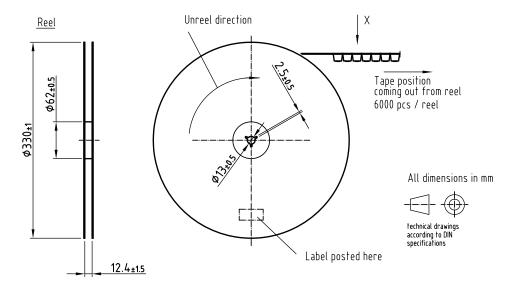


Dimensions in mm

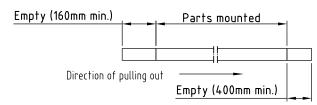


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TAPING AND REEL DIMENSIONS in millimeters: VSMF2893RGX01

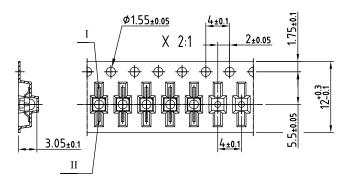


Leader and trailer tape:



Terminal position in tape

Device	Lead I	Lead II			
VSMB2943RGX01					
VSMF2893RGX01					
VEMD2x03X01	Cathode Anode				
VEMT2x03X01	Collector	Emitter			
	Cottector	Cilii I Ci			
VSMY2853RG	Anode	Cathode			



Drawing refers to following types: Reel dimensions and tape

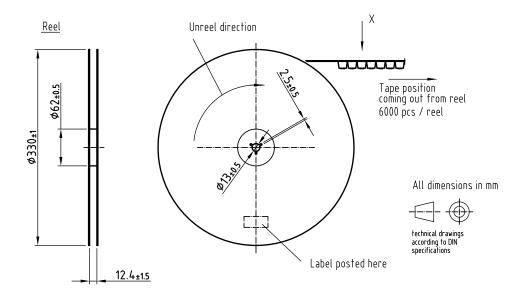
see table

Drawing-No.: 9.800-5100.02-4 Issue: prel; 03.08.12

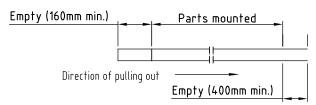


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TAPING AND REEL DIMENSIONS in millimeters: VSMF2893GX01



Leader and trailer tape:



<u>Terminal p</u>	osition in	tape		T	ſ	Ø1.5!	5±0.05		4	±0 <u>.1</u>	
Device	Lead I	Lead II		<u> </u>	. /		Χ	2:1	↓.		_
VSMB2943GX01					\						
VSMF2893GX01	Cathode	Anode	1	4	1	<u>—</u>	<u>—</u>	<u>—</u>	ф	Te	
VEMD2x23X01	Carriode	Alloue	liode	ľ.	Γ_{-}					$\perp^{\!$	
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VEMT2x23X01	Collector	Emitter				יון עי			וויייייייייייייייייייייייייייייייייייי	Щ	4
			ן מ	⊢	1					١,	+
VSMY2853G	Anode	Cathode		3.05±0.1						4±0	1
				II	1						

Drawing refers to following types: see table Reel dimensions and tape

Drawing-No.: 9.800-5091.21-4 Issue: prel; 03.08.12

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